

ROITHNER LASERTECHNIK GIRDH

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LED36-TEC-PR

TECHNICAL DATA



Mid-Infrared Light Emitting Diode

Light Emitting Diodes with central wavelength 3.65 μ m series are based on heterostructures grown on InAs substrates by MOCVD. InAsSb is used in the active layer. Wide band gap solid solutions InAsSbP with P content 50% are used for good electron confinement.

LED36-SMD3 has a stable ouput power and a lifetime more then 80000 hours.

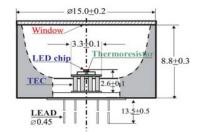
Features

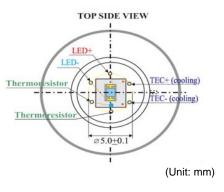
- Structure: InAsSb/InAsSbP
- Peak Wavelength: typ. 3.65 μm
- Optical Ouput Power: typ. 30 μW qCW
- Package: TO-5, with TEC, thermistor, PR and window



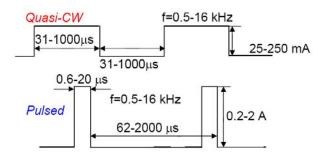
Specifications

| ltem | Condition | Rating | | | Unit |
|---------------------------|--|--------|------|------|-------|
| Item | Condition | Min. | Тур. | Max. | Oilit |
| Peak Wavelength | T=300 K | 3.60 | 3.65 | 3.70 | μm |
| FWHM | 150 mA CW | 0.40 | 0.50 | 0.60 | μm |
| Quasi-CW Optical Power | 200 mA qCW | 20 | 30 | 40 | μW |
| Pulsed Optical Power | 1 A | 180 | 200 | 220 | mW |
| Switching Time | T=300 K | 10 | 20 | 30 | ns |
| Operation Voltage | 200 mA qCW | 0.2 | - | 1.0 | V |
| Operating Temperature | -240 + 50 | | | | °C |
| Emitting Area | 300x300 | | | | μm |
| Soldering Temperature | 180 | | | | °C |
| Package | TO-5, with built-in thermocooler, thermoresistor, parabolic reflector and window | | | | |





Operating Regime



Quasi-CW

- Maximum current 220 mA
- Recommended current 150-200mA

Pulsed

 Maximum current 1 A (puls lenght 500 ns, repetition rate 2kHz)

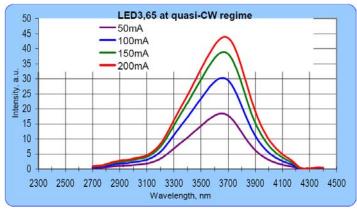


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Typical Performance Curves



WIEDNER HAUPTSTRASSE 76

